

SEMITOP® 3

3-phase bridge rectifier +
brake chopper + 3-phase
bridge inverter
SK 25 DGD L 063

Target Data

Features

- Clearance and creepage distances in compliance UL508
- Low tail current with low temperature dependence
- One screw mounting
- Compact design
- High short circuit capability

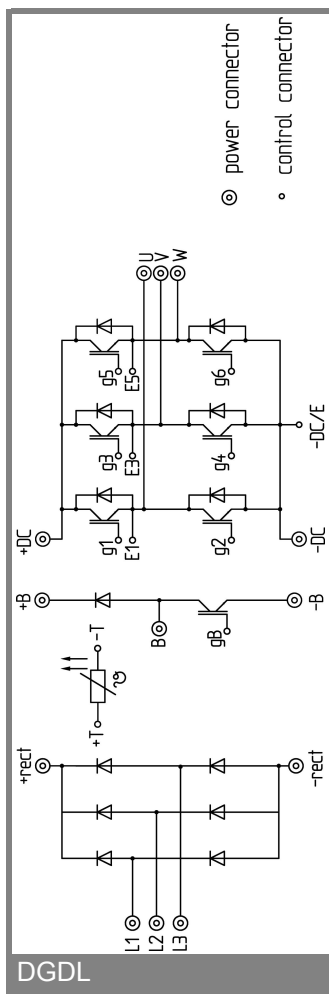
Typical Applications

- Inverter up to 10,0 kVA
- Typical motor power 4,0 kW

DGD L

Absolute Maximum Ratings		$T_s = 25\text{ °C}$, unless otherwise specified	
Symbol	Conditions	Values	Units
IGBT - Inverter (IGBT Chopper see SK 10 DGD L 063 data sheet)			
V_{CES}		600	V
I_C	$T_s = 25\text{ (80) °C}$	32 (22)	A
I_{CRM}	$T_s = 25\text{ (80) °C}$, $t_p \leq 1\text{ ms}$	64 (44)	A
V_{GES}		± 20	V
T_j		- 40 ... + 150	°C
Diode - Inverter (Diode Chopper see SK 10 DGD L 063 data sheet)			
I_F	$T_s = 25\text{ (80) °C}$	36 (24)	A
I_{FRM}	$T_s = 25\text{ (70) °C}$, $t_p \leq 1\text{ ms}$	72 (48)	A
T_j		- 40 ... + 150	°C
Diode - Rectifier			
V_{RRM}		800	V
I_F	$T_s = 80\text{ °C}$	25	A
I_{FSM}	$t_p = 10\text{ ms}$, $\sin 180\text{ °}$, $T_j = 150\text{ °C}$	270	A
i^2t	$t_p = 10\text{ ms}$, $\sin 180\text{ °}$, $T_j = 150\text{ °C}$	365	A²s
T_j		- 40 ... + 150	°C
I_{tRMS}	per power terminal (20 A / spring)		A
T_{stg}	$T_{op} \leq T_{stg}$	- 40 ... + 125	°C
V_{isol}	AC, 1 min.	2500	V

Characteristics		$T_s = 25\text{ °C}$, unless otherwise specified		
Symbol	Conditions	min.	typ.	max. Units
IGBT - Inverter (IGBT Chopper see SK 10 DGD L 063 data sheet)				
V_{CEsat}	$I_C = 25\text{ A}$, $T_j = 25\text{ (125) °C}$		1,9 (2,1)	V
$V_{GE(th)}$	$V_{GE} = V_{CE}$, $I_C = 0,5\text{ mA}$		5,5	V
$V_{CE(TO)}$	$T_j = 25\text{ (125) °C}$			V
r_T	$T_j = 25\text{ (125) °C}$			mΩ
C_{ies}	$V_{CE} = 25\text{ V}$, $V_{GE} = 0\text{ V}$, $f = 1\text{ MHz}$		1,6	nF
C_{oes}	$V_{CE} = 25\text{ V}$, $V_{GE} = 0\text{ V}$, $f = 1\text{ MHz}$		-	nF
C_{res}	$V_{CE} = 25\text{ V}$, $V_{GE} = 0\text{ V}$, $f = 1\text{ MHz}$		-	nF
$R_{th(j-s)}$	per IGBT			1,4 K/W
$t_{d(on)}$	under following conditions		-	ns
t_r	$V_{CC} = 300\text{ V}$, $V_{GE} = \pm 15\text{ V}$		-	ns
$t_{d(off)}$	$I_C = 25\text{ A}$, $T_j = 125\text{ °C}$		-	ns
t_f	$R_{Gon} = R_{Goff} = 33\text{ Ω}$		-	ns
E_{on}	inductive load		0,8	mJ
E_{off}			0,8	mJ
Diode - Inverter (Diode Chopper see SK 10 DGD L 063 data sheet)				
$V_F = V_{EC}$	$I_F = 25\text{ A}$, $T_j = 25\text{ (125) °C}$		1,45 (1,4)	V
$V_{(TO)}$	$T_j = 25\text{ (125) °C}$		(0,85)	V
r_T	$T_j = 25\text{ (125) °C}$		(22)	mΩ
$R_{th(j-s)}$	per diode			1,7 K/W
I_{RRM}	under following conditions		-	A
Q_{rr}	$I_F = 30\text{ A}$, $V_R = 300\text{ V}$		-	μC
E_{rr}	$V_{GE} = 0\text{ V}$, $T_j = 125\text{ °C}$		0,56	mJ
	$di_F/dt = -\text{A}/\mu\text{s}$			
Diode Rectifier				
V_F	$I_F = 25\text{ A}$, $T_j = 25\text{ °C}$		1,1	V
$V_{(TO)}$	$T_j = 150\text{ °C}$		0,8	V
r_T	$T_j = 150\text{ °C}$		13	mΩ
$R_{th(j-s)}$	per diode			1,7 K/W
Temperature Sensor				
R_{ts}	3 %, $T_r = 25\text{ (100) °C}$		1000(1670)	Ω
Mechanical Data				
w				g
M_s	Mounting torque	2	2,5	Nm



All dimensions are in mm.
 Suggested Hole diameter for solder pins and
 plastic pins: 2mm.

pinout, dimensions

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

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